

# Plastic Silicon Photodiode

## QSD2030F

### Features

- PIN Photodiode
- Package Type: T-1 3/4 (5 mm Lens Diameter)
- Wide Reception Angle, 40°
- Daylight Filter
- Package Material and Color: Black Epoxy
- High Sensitivity
- Peak Sensitivity  $\lambda = 880 \text{ nm}$
- Radiant Sensitive Area: 1.245 mm x 1.245 mm
- This is a Pb-Free Device

### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
$T_{OPR}$	Operating Temperature	-40 to +100	°C
$T_{STG}$	Storage Temperature	-40 to +100	°C
$T_{SOL-I}$	Soldering Temperature (Iron) (Note 1), (Note 2), (Note 3)	240 for 5 s	°C
$T_{SOL-F}$	Soldering Temperature (Flow) (Note 1), (Note 2)	260 for 10 s	°C
$V_{BR}$	Reverse Breakdown Voltage	50	V
$P_D$	Power Dissipation (Note 4)	150	mW

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

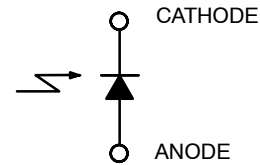
1. RMA flux is recommended
2. Methanol or isopropyl alcohols are recommended as cleaning agents.
3. Soldering iron tip 1/16 inch (1.6 mm) minimum from housing..
4. Derate power dissipation linearly 1.33 mW/°C above 25°C.

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ )

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
$\lambda_{PS}$	Peak Sensitivity Wavelength		-	880	-	nm
$\lambda_{SR}$	Wavelength Sensitivity Range		700	-	1100	nm
$\Theta$	Reception Angle		-	$\pm 20$	-	°
$V_F$	Forward Voltage	$I_F = 80 \text{ mA}$	-	1.3	-	V
$I_D$	Reverse Dark Current	$V_R = 10 \text{ V}, E_e = 0$	-	-	10	nA
$I_L$	Reverse Light Current	$E_e = 0.5 \text{ mW/cm}^2, V_R = 5 \text{ V}, \lambda = 950 \text{ nm}$	15	25	-	$\mu\text{A}$
$V_O$	Open Circuit Voltage	$E_e = 0.5 \text{ mW/cm}^2, \lambda = 880 \text{ nm}$	-	420	-	mV
$TC_V$	Temperature Coefficient of $V_O$		-	+0.6	-	mV / K
$I_{SC}$	Short Circuit Current	$E_e = 0.5 \text{ mW/cm}^2, \lambda = 880 \text{ nm}$	-	50	-	$\mu\text{A}$
$TC_I$	Temperature Coefficient of $I_{SC}$		-	+0.3	-	% / K
C	Capacitance	$V_R = 0, f = 1 \text{ MHz}, E_e = 0$	-	15	-	pF
$t_r$	Rise Time	$V_R = 5 \text{ V}, R_L = 50 \Omega, \lambda = 950 \text{ nm}$	-	5	-	ns
$t_f$	Fall Time		-	5	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

### SCHEMATIC



T-1 3/4, 5MM PHOTODIODE  
CASE 100CF

### ORDERING INFORMATION

Device	Package	Shipping
QSD2030F	T-1 3/4, 5MM PHOTODIODE (Pb-Free)	250 / Bulk Bag

TYPICAL PERFORMANCE CHARACTERISTICS

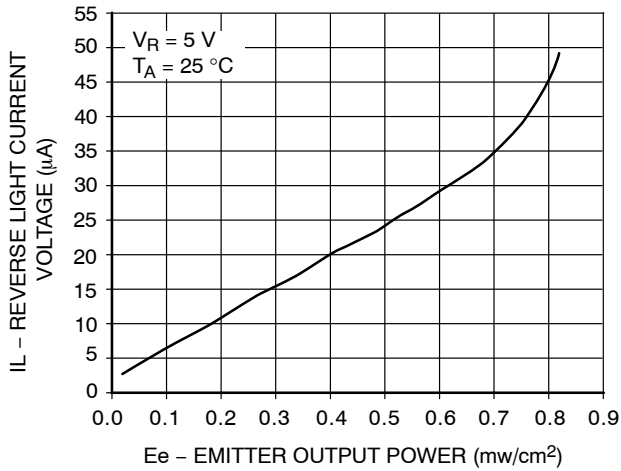


Figure 1. Reverse Light Current vs. Emitter Output Power

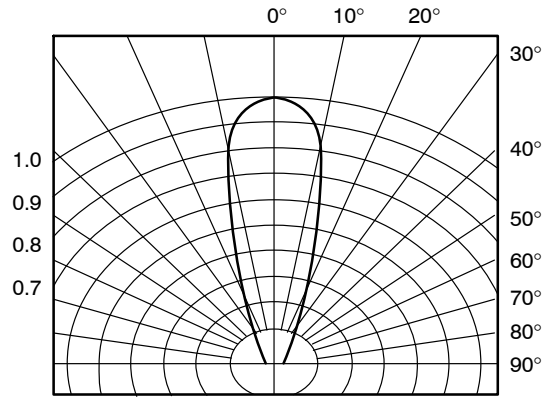


Figure 2. Angular Response

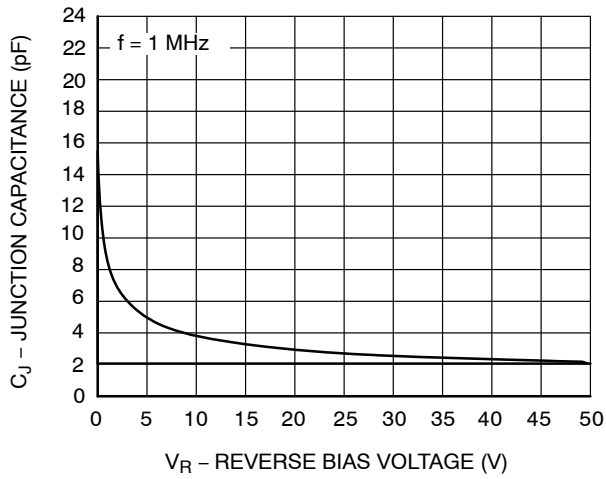


Figure 3. Capacitance vs. Reverse Voltage

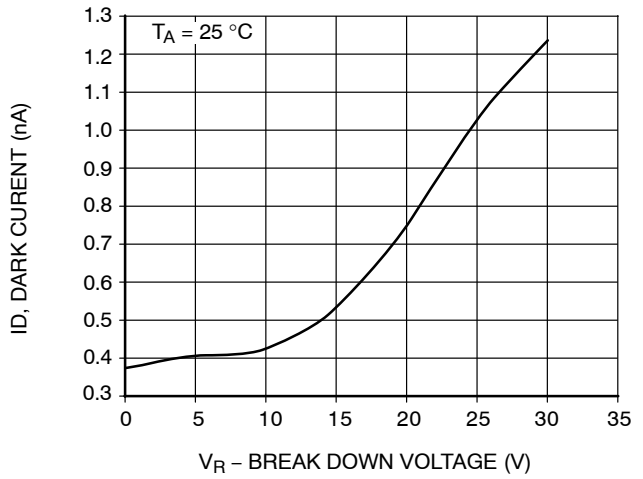
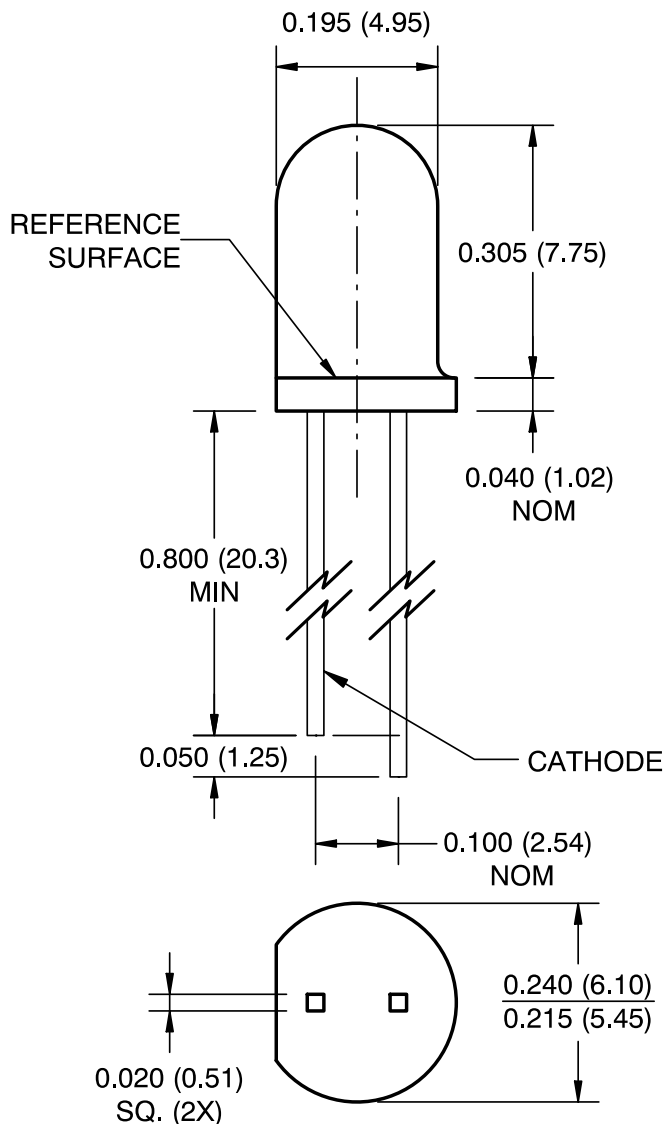


Figure 4. Dark Current vs. Reverse Voltage



**T-1 3/4, 5MM PHOTODIODE**  
CASE 100CF  
ISSUE 0

DATE 30 NOV 2016



**Notes:**

1. Dimensions for all drawings are in inches (mm).
2. Tolerance of  $\pm 0.010$  (0.25) on all non-nominal dimensions unless otherwise specified.

<b>DOCUMENT NUMBER:</b>	<b>98AON13431G</b>	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
<b>DESCRIPTION:</b>	<b>T-1 3/4, 5MM PHOTODIODE</b>	<b>PAGE 1 OF 1</b>

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

**onsemi**, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## ADDITIONAL INFORMATION

### TECHNICAL PUBLICATIONS:

Technical Library: [www.onsemi.com/design/resources/technical-documentation](http://www.onsemi.com/design/resources/technical-documentation)  
onsemi Website: [www.onsemi.com](http://www.onsemi.com)

### ONLINE SUPPORT: [www.onsemi.com/support](http://www.onsemi.com/support)

For additional information, please contact your local Sales Representative at [www.onsemi.com/support/sales](http://www.onsemi.com/support/sales)